

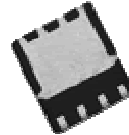
## P-Channel 100-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low  $r_{DS(on)}$  and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low  $r_{DS(on)}$  provides higher efficiency and extends battery life
- Low thermal impedance copper leadframe DFN3x3-8PP saves board space
- Fast switching speed
- High performance trench technology

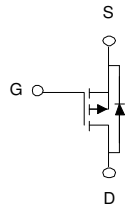
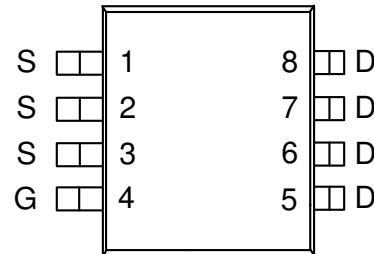


**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**



DFN3x3-8PP

Top View



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Maximum	Units
Drain-Source Voltage		$V_{DS}$	-100	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	
Continuous Drain Current <sup>a</sup>	$T_A = 25^\circ\text{C}$	$I_D$	-3	A
	$T_A = 70^\circ\text{C}$		-2.5	
Pulsed Drain Current <sup>b</sup>		$I_{DM}$	$\pm 50$	
Continuous Source Current (Diode Conduction) <sup>a</sup>		$I_S$	-2.1	A
Power Dissipation <sup>a</sup>	$T_A = 25^\circ\text{C}$	$P_D$	3.5	W
	$T_A = 70^\circ\text{C}$		2.0	
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55 to 150	$^\circ\text{C}$

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Maximum	Units
Maximum Junction-to-Ambient <sup>a</sup>	$t \leq 10 \text{ sec}$	$R_{\theta JA}$	35	$^\circ\text{C/W}$
	Steady State		81	$^\circ\text{C/W}$

### Notes

- Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature

**SPECIFICATIONS ( $T_A = 25^\circ\text{C}$  UNLESS OTHERWISE NOTED)**

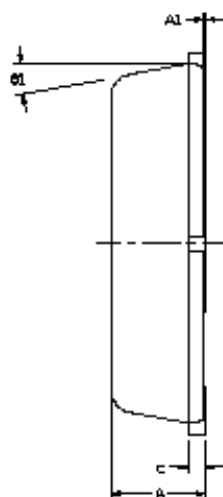
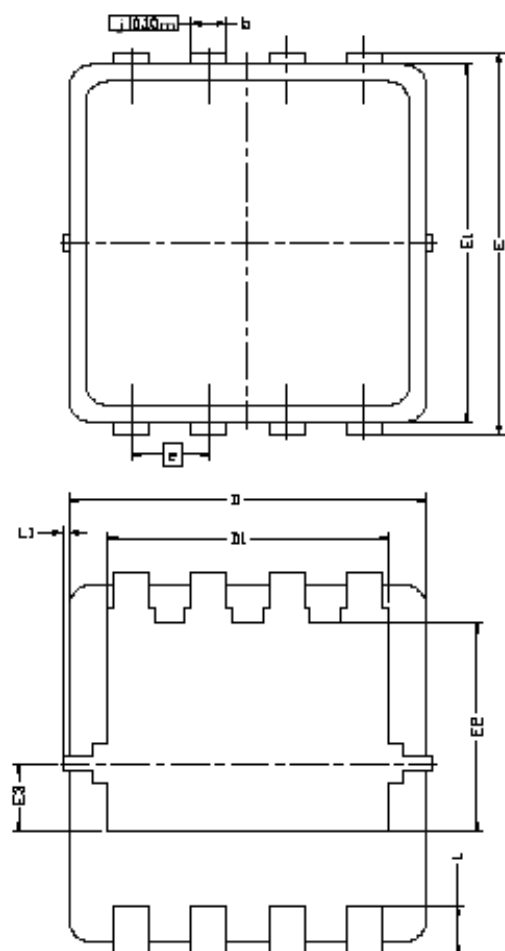
Parameter	Symbol	Test Conditions	Limits			Unit
			Min	Typ	Max	
Static						
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \mu A$	-1			V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			$\pm 10$	$\mu A$
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}$			-1	$\mu A$
		$V_{DS} = -80 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}C$			-5	
On-State Drain Current <sup>A</sup>	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-50			A
Drain-Source On-Resistance <sup>A</sup>	$r_{DS(on)}$	$V_{GS} = -10 \text{ V}, I_D = -1 \text{ A}$			269	m $\Omega$
		$V_{GS} = -5.5 \text{ V}, I_D = -1 \text{ A}$			289	
Forward Tranconductance <sup>A</sup>	$g_{fs}$	$V_{DS} = -15 \text{ V}, I_D = -1 \text{ A}$		29		S
Diode Forward Voltage	$V_{SD}$	$I_S = 2.5 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS} = -15 \text{ V}, V_{GS} = -5.5 \text{ V}, I_D = -1 \text{ A}$		8		nC
Gate-Source Charge	$Q_{gs}$			3		
Gate-Drain Charge	$Q_{gd}$			3		
Input Capacitance	$C_{iss}$	$V_{DS}=-15V, V_{GS}=0V, f=1MHz$		1300		pF
Output Capacitance	$C_{oss}$			130		
Reverse Transfer Capacitance	$C_{rss}$			70		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = -15 \text{ V}, R_L = 6 \Omega, I_D = -1 \text{ A}, V_{GEN} = -10 \text{ V}$		5		nS
Rise Time	$t_r$			4		
Turn-Off Delay Time	$t_{d(off)}$			60		
Fall-Time	$t_f$			40		

## Notes

- Pulse test:  $PW \leq 300 \mu\text{s}$  duty cycle  $\leq 2\%$ .
- Guaranteed by design, not subject to production testing.

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# Package Information



DIM.	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.700	0.80	0.900	0.0276	0.0315	0.0354
A1	0.00	---	0.05	0.000	---	0.002
b	0.24	0.30	0.35	0.009	0.012	0.014
c	0.10	0.152	0.25	0.004	0.006	0.010
D	3.00 BSC			0.118 BSC		
D1	2.35 BSC			0.093 BSC		
E	3.20 BSC			0.126 BSC		
E1	3.00 BSC			0.118 BSC		
E2	1.75 BSC			0.069 BSC		
E3	0.575 BSC			0.023 BSC		
e	0.65 BSC			0.026 BSC		
L	0.30	0.40	0.50	0.0118	0.0157	0.0197
L1	0	---	0.100	0	---	0.004
Ø1	0°	10°	12°	0°	10°	12°